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16-BIT TO 8-BIT MULTIPLEXER/DEMULTIPLEXER GIGABIT ETHERNET LAN SWITCH WITH POWER DOWN MODE

Check for Samples: TS3L501E

FEATURES

- Integrated Power Down Mode
- Wide Bandwidth (BW = 600 MHz Typ)
- Low Crosstalk (X_{TALK} = −37 dB Typ @ 250 MHz)
- Low Bit-to-Bit Skew (t_{sk(o)} = 100 ps Max)
- Low and Flat ON-State Resistance (r_{on} = 4 Ω Typ, r_{on(flat)} = 0.5 Ω Typ)
- Low Input/Output Capacitance (C_{ON} = 9 pF Typ)
- Rail-to-Rail Switching on Data I/O Ports (0 to 3.6 V)
- V_{CC} Operating Range From 3 V to 3.6 V
- Support Power Down Mode
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance (A, B, C, LED pins)
 - ± 4-kV IEC61000-4-2, Contact Discharge
 - 6-kV Human Body Model Per
 JESD22-A114E (Switch I/O pins to GND)
- ESD Performance (All pins)
 - 2-kV Human Body Model Per JESD22-A114E

APPLICATIONS

- 10/100/1000 Base-T Signal Switching
- Differential (LVDS, LVPECL) Signal Switching
- Audio/Video Switching
- Hub and Router Signal Switching

RUA PACKAGE (TOP VIEW) (38 A_0 (37 В (36 C_0 V_{DD} (35 C_1 4 (34 PD B₂ A_2 (33 B_3 C_2 A_3 7) (32 V_{DD} 8 (31 C_3 Exposed Center Pad 9) (30 V_{DD} A_4 (GND) A₅ 29 В A_6 11) (28 B_5 A_7 12) (27 C_{Λ} SEL (26 C_5 14) V_{DD} (25 B_6 LED_A₀ (24 B_7 LED_A₁ C_6 (23 16) LED_B₀ (22 C₇ ပ် \circ

The exposed center pad must be connected to GND.

DESCRIPTION/ORDERING INFORMATION

The TS3L501E is a 16-bit to 8-bit multiplexer/demultiplexer LAN switch with a single select (SEL) input and Power down Mode input. The device provides additional I/Os for switching status indicating LED signals and includes high ESD protection. SEL input controls the data path of the multiplexer/demultiplexer. Power down input can put the device into the standby mode for minimizing current consumption per mode selection.

The device provides a low and flat ON-state resistance (Ron) and an excellent ON-state resistance match. Low input/output capacitance, high bandwidth, low skew, and low crosstalk among channels make this device suitable for various LAN applications, such as 10/100/1000 Base-T. This device can be used to replace mechanical relays in LAN applications. It also can be used to route signals from a 10/100 Base-T Ethernet transceiver to the RJ-45 LAN connectors in laptops or in docking stations.

It is characterized for operation over the free-air temperature range of -40°C to 85°C.



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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

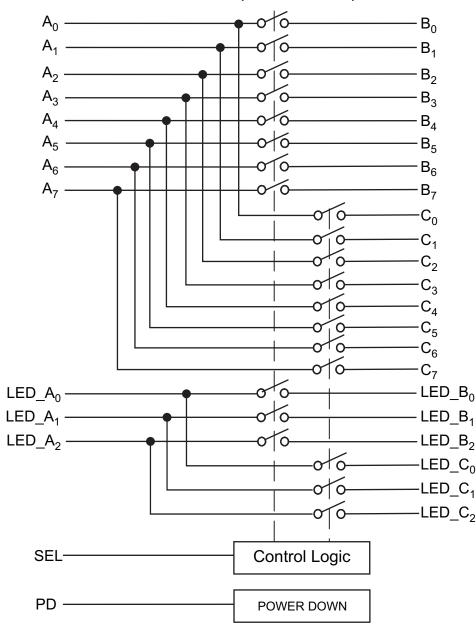


Table 1. ORDERING INFORMATION

T _A	PACKAGE	(1) (2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	TQFN – RUA	Tape and reel	TS3L501ERUAR	TK501E

- Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
 For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

LOGIC DIAGRAM (POSITIVE LOGIC)





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FUNCTION TABLE

PD	SEL	FUNCTION
L	L	A_n to B_n , LED_ A_n to LED_ B_n
L	Н	A_n to C_n , LED_ A_n to LED_ C_n
Н	X	Hi-Z

PIN DESCRIPTION

NAME	DESCRIPTION
A _n	Port A DeMux I/O
B _n , C _n	Port B, C Mux I/O
LED_A _n , LED_B _n , LED_C _n	LED Mux I/O
SEL	Select Input
PD	Power Down Input, Active High
GND	Ground
V_{DD}	Power

ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

	peraung nee-an temperature range (um	coo otherwise noted)			
			MIN	MAX	UNIT
V_{DD}	Supply voltage range		-0.5	4.6	V
V _{IN}	Control input voltage range (2) (3)		-0.5	7	V
V _{I/O}	Switch I/O voltage range ^{(2) (3) (4)}		-0.5	7	V
I _{IK}	Control input clamp current	V _{IN} < 0		-50	mA
I _{I/OK}	I/O port clamp current	V _{I/O} < 0		-50	mA
I _{I/O}	ON-state switch current ⁽⁵⁾			±128	mA
	Continuous current through V _{DD} or GND			±100	mA
θ_{JA}	Package thermal impedance (6)			51.2	°C/W
T _{stg}	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- All voltages are with respect to ground, unless otherwise specified.
- The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- V_I and V_O are used to denote specific conditions for $V_{I/O}$.
- $I_{\rm I}$ and $I_{\rm O}$ are used to denote specific conditions for $I_{\rm I/O}$. The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS(1)

		MIN	MAX	UNIT
V_{DD}	Supply voltage	3	3.6	V
V_{IH}	High-level control input voltage (SEL)	2	5.5	V
V_{IL}	Low-level control input voltage (SEL)	0	8.0	V
V_{IN}	Input voltage (SEL)	0	5.5	V
V _{I/O}	Input/output voltage	0	V_{DD}	V
T _A	Operating free-air temperature	-40	85	°C

(1) All unused control inputs of the device must be held at V_{DD} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

Product Folder Link(s): TS3L501E



ELECTRICAL CHARACTERISTICS

for 1000 Base-T Ethernet switching over recommended operating free-air temperature range, V_{DD} = 3.3 V ± 0.3 V

(unless otherwise noted)

PARAMETER			TEST CONDITIONS ⁽¹⁾					MAX	UNIT
V_{IK}	SEL, PD	$V_{DD} = 3.6 \text{ V},$	$I_{IN} = -18 \text{ mA}$				-0.7	-1.2	V
I _{IH}	SEL, PD	$V_{DD} = 3.6 \text{ V},$	$V_{IN} = V_{DD}$					±2	μΑ
I _{IL}	SEL, PD	$V_{DD} = 3.6 \text{ V},$	$V_{IN} = GND$					±1	μΑ
I _{OFF}	SEL, PD	$V_{DD} = 0 V$,	$V_{IN} = 0 \text{ to } 3.6 \text{ V}$					±1	μΑ
I _{CC}		$V_{DD} = 3.6 \text{ V},$	$I_{I/O} = 0$,	Switch ON or OI	FF		250	600	μΑ
I _{CC_PD}		$V_{DD} = 3.6 \text{ V},$	$V_{IN} = 3.6 V,$	PD = High			1		
C _{IN}	SEL, PD	f = 1 MHz,	$V_{IN} = 0$				2.6	3.0	pF
C _{OFF}	B or C port	$V_I = 0$,	f = 1 MHz,	Outputs open,	Switch OFF		3	4	pF
C _{ON}		$V_I = 0$,	f = 1 MHz,	Outputs open,	Switch ON		9	9.8	pF
r _{on}		$V_{DD} = 3 V$,	$1.5 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{DD}},$	$I_O = -40 \text{ mA}$			4	8	Ω
r _{on(flat)} (3)		$V_{DD} = 3 V$,	$V_I = 1.5 \text{ V} \text{ and } V_{DD}$	$I_O = -40 \text{ mA}$			0.7		Ω
Δr_{on} (4)		V _{DD} = 3 V,	$1.5 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{DD}},$	$I_O = -40 \text{ mA}$			0.8	1.5	Ω

- $V_{I},\,V_{O},\,I_{I},\,$ and I_{O} refer to I/O pins. V_{IN} refers to the control inputs. All typical values are at $V_{DD}=3.3$ V (unless otherwise noted), $T_{A}=25^{\circ}C.$ $r_{on(flat)}$ is the difference of r_{on} in a given channel at specified voltages. Δr_{on} is the difference of r_{on} from center (A_4, A_5) ports to any other port.
- (3)

ELECTRICAL CHARACTERISTICS

for 10/100 Base-T Ethernet switching over recommended operating free-air temperature range, V_{DD} = 3.3 V \pm 0.3 V

(unless otherwise noted)

\a	PARAMETER TEST CONDITIONS ⁽¹⁾								
PARAMETER			TEST COI	TEST CONDITIONS ⁽¹⁾				MAX	UNIT
V_{IK}	SEL, PD	$V_{DD} = 3.6 V,$	$I_{IN} = -18 \text{ mA}$				-0.7	-1.2	V
I _{IH}	SEL, PD	$V_{DD} = 3.6 \text{ V},$	$V_{IN} = V_{DD}$					±2	μΑ
I _{IL}	SEL, PD	$V_{DD} = 3.6 \text{ V},$	$V_{IN} = GND$					±1	μΑ
I _{OFF}	SEL, PD	$V_{DD} = 0 V$,	$V_{IN} = 0 \text{ to } 3.6 \text{ V}$					±1	μΑ
I _{CC}	•	$V_{DD} = 3.6 \text{ V},$	$I_{I/O} = 0$,	Switch ON or OFF			250	600	μΑ
I _{CC_PD}		$V_{DD} = 3.6 \text{ V},$	V _{IN} = 3.6 V,	PD = High			1		
C _{IN}	SEL, PD	f = 1 MHz,	V _{IN} = 0				2.6	3.0	pF
C _{OFF}	B or C port	$V_I = 0$,	f = 10 MHz,	Outputs open,	Switch OFF		3	4	pF
C _{ON}		$V_I = 0$,	f = 10 MHz,	Outputs open,	Switch ON		9	9.8	pF
r _{on}		$V_{DD} = 3 V$,	$1.25 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{DD}},$	$I_O = -10$ mA to -30 mA			4	6	Ω
r _{on(flat)}	(3)	$V_{DD} = 3 V$,	$V_I = 1.25 \text{ V} \text{ and } V_{DD},$	$I_{O} = -10 \text{ mA to } -30 \text{ mA}$			0.5		Ω
Δr_{on} (4)		$V_{DD} = 3 V$,	$1.25 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{DD}},$	$I_{O} = -10 \text{ mA to } -30 \text{ mA}$			0.8	1.5	Ω

- $V_{I},\,V_{O},\,I_{I},\,$ and I_{O} refer to I/O pins. V_{IN} refers to the control inputs. All typical values are at $V_{DD}=3.3$ V (unless otherwise noted), $T_{A}=25^{\circ}C.$ $r_{on(flat)}$ is the difference of r_{on} in a given channel at specified voltages. Δr_{on} is the difference of r_{on} from center (A4, A5) ports to any other port.
- (3)



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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, V_{DD} = 3.3 V ± 0.3 V, R_L = 200 Ω , C_L = 10 pF (unless otherwise noted) (see Figure 5 and Figure 6)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{pd} ⁽²⁾	A or B/C	B/C or A		0.3		ns
t _{PZH} , t _{PZL}	SEL	A or B/C	0.5		15	ns
t _{PHZ} , t _{PLZ}	SEL	A or B/C	0.9		9	ns
t _{sk(o)} (3)	A or B/C	B/C or A		50	100	ps
t _{sk(p)} (4)	A or B/C	B/C or A		50	100	ps
t _{ON} /t _{OFF} (5)	PD	A or B/C			250	ns

- All typical values are at V_{DD} = 3.3 V (unless otherwise noted), T_A = 25°C. The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance). Output skew between center port (A_4 to A_5) to any other port
- Skew between opposite transitions of the same output in a given device |t_{PHL} t_{PLH}|
- Device enable/disable time from PD

DYNAMIC CHARACTERISTICS

over recommended operating free-air temperature range, V_{DD} = 3.3 V ± 0.3 V (unless otherwise noted)

PARAMETER	İ	TEST CONDITIONS					
X _{TALK}	$R_L = 50 \Omega$,	$_{-}$ = 50 Ω , f = 250 MHz, See Figure 8					
O _{IRR}	$R_L = 50 \Omega$,	f = 250 MHz,	See Figure 9	-37	dB		
BW		See Figure 7		600	MHz		

(1) All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C.



OPERATING CHARACTERISTICS

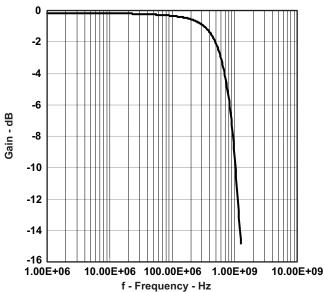
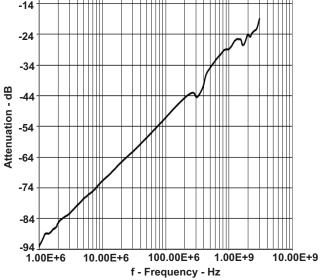
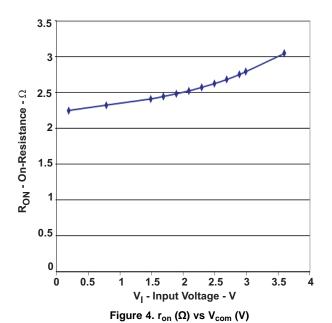


Figure 1. Gain vs Frequency Figure 2. OFF Isolation vs Frequency



-19.97 -29.97 -39.97 -49.97 -69.97 -89.97 -99.97 -109.97 1.00E+6 10.00E+6 1.00E+9 10.00E+9 f - Frequency - Hz

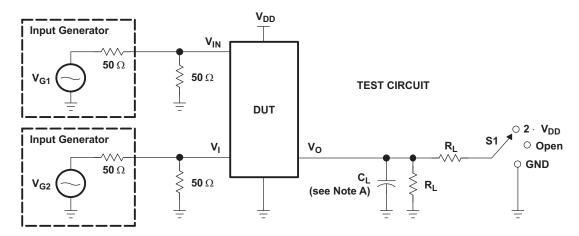
Figure 3. Crosstalk vs Frequency



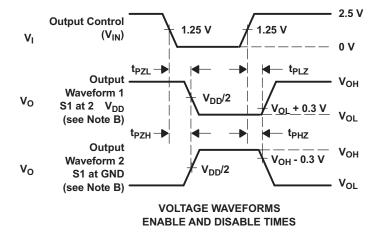


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PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)



TEST	V _{DD}	S1	R_L	V _{in}	CL	$\mathbf{V}_{\!\Delta}$
t _{PLZ} /t _{PZL}	3.3 V	2 · V _{DD}	200 Ω	GND	10 pF	0.3 V
t _{PHZ} /t _{PZH}	3.3 V	GND	200 Ω	V _{DD}	10 pF	0.3 V



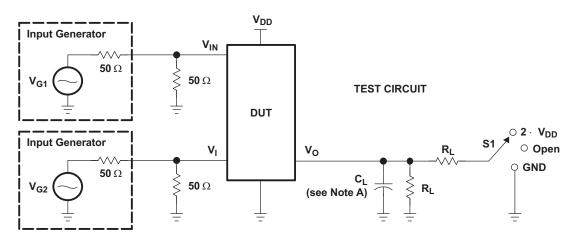
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω , $t_{f} \leq$ 2.5 ns, $t_{f} \leq$ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en} .

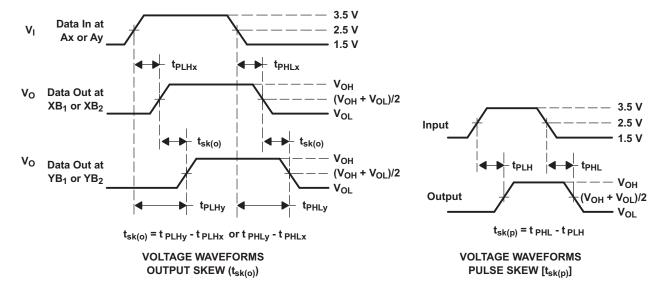
Figure 5. Test Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION (Skew)



TEST	V _{DD}	S1	R _L	V _{in}	CL
t _{sk(o)}	3.3 V \pm 0.3 V	Open	200 Ω	V _{DD} or GND	10 pF
t _{sk(p)}	3.3 V ± 0.3 V	Open	200 Ω	V _{DD} or GND	10 pF



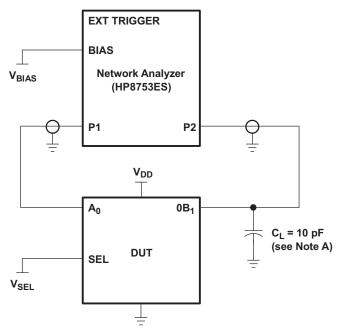
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_0 = 50 Ω , $t_r \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.

Figure 6. Test Circuit and Voltage Waveforms

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PARAMETER MEASUREMENT INFORMATION



A. C_L includes probe and jig capacitance.

Figure 7. Test Circuit for Frequency Response (BW)

Frequency response is measured at the output of the ON channel. For example, when $V_{SEL}=0$ and A_0 is the input, the output is measured at $0B_1$. All unused analog I/O ports are left open.

HP8753ES Setup

Average = 4

RBW = 3 kHz

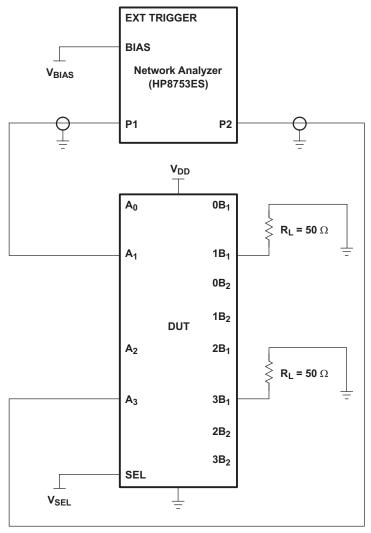
 $V_{BIAS} = 0.35 \text{ V}$

ST = 2 s

P1 = 0 dBM



PARAMETER MEASUREMENT INFORMATION (continued)



- A. C_L includes probe and jig capacitance.
- B. A $50-\Omega$ termination resistor is needed to match the loading of the network analyzer.

Figure 8. Test Circuit for Crosstalk (X_{TALK})

Crosstalk is measured at the output of the nonadjacent ON channel. For example, when $V_{SEL} = 0$ and A_1 is the input, the output is measured at A_3 . All unused analog input (A) ports are connected to GND, and output (B) ports are left open.

HP8753ES Setup

Average = 4

RBW = 3 kHz

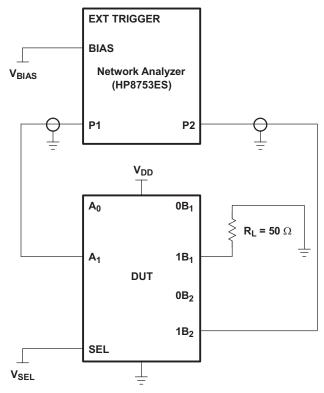
 $V_{BIAS} = 0.35 V$

ST = 2 s

P1 = 0 dBM

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PARAMETER MEASUREMENT INFORMATION (continued)



- A. C_L includes probe and jig capacitance.
- B. A 50-Ω termination resistor is needed to match the loading of the network analyzer.

Figure 9. Test Circuit for OFF Isolation (OIRR)

OFF isolation is measured at the output of the OFF channel. For example, when V_{SEL} = GND and A_1 is the input, the output is measured at $1B_2$. All unused analog input (A) ports are connected to ground, and output (B) ports are left open.

HP8753ES Setup

Average = 4

RBW = 3 kHz

 $V_{BIAS} = 0.35 V$

ST = 2 s

P1 = 0 dBM



PACKA

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Pe
TS3L501ERUAR	ACTIVE	WQFN	RUA	42	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retard in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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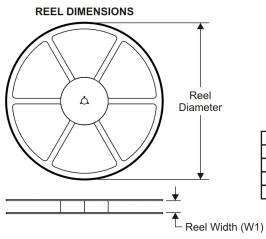
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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

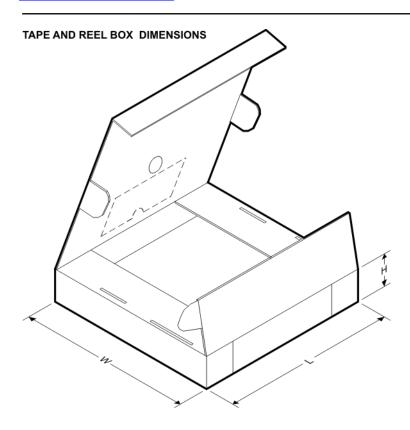


*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3L501ERUAR	WQFN	RUA	42	3000	330.0	16.4	3.8	9.3	1.0	8.0	16.0	Q1

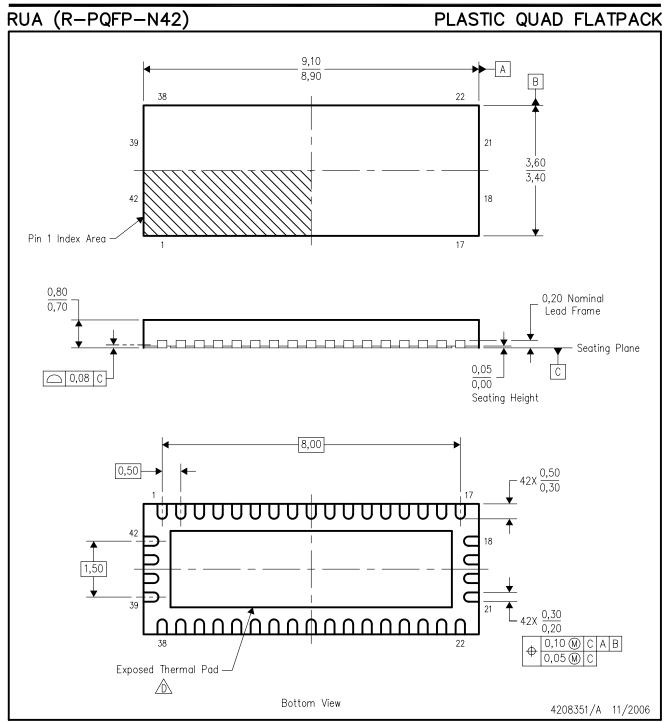
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*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
I	TS3L501ERUAR	WQFN	RUA	42	3000	358.0	335.0	35.0



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.



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